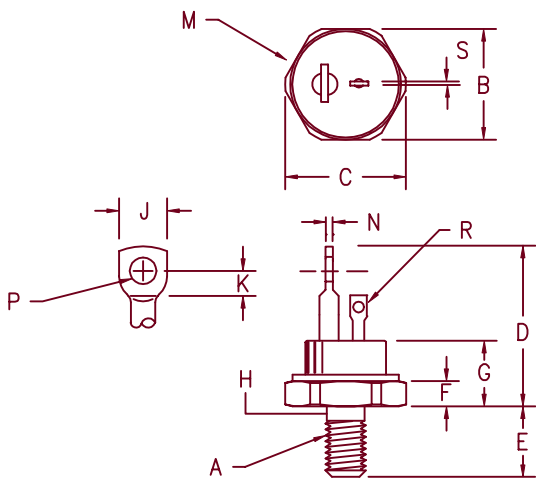


Silicon Controlled Rectifier Series 40C



Note 1: 1/4-28 UNF-3A

Note 2: Full thread within 2 1/2 threads

| Dim. | Inches | | Millimeter | | Notes |
|------|---------|---------|------------|---------|-------|
| | Minimum | Maximum | Minimum | Maximum | |
| A | --- | --- | --- | --- | 1 |
| B | .677 | .685 | 17.20 | 17.40 | |
| C | --- | .770 | --- | 19.56 | |
| D | 1.200 | 1.250 | 30.48 | 31.75 | |
| E | .427 | .447 | 10.84 | 11.35 | |
| F | .115 | .155 | 2.92 | 3.94 | |
| G | --- | .515 | --- | 13.08 | |
| H | --- | .249 | --- | 6.32 | 2 |
| J | .200 | .300 | 5.08 | 7.62 | |
| K | .120 | --- | 3.05 | --- | |
| M | --- | .667 | --- | 16.94 | Dia. |
| N | .065 | .085 | 1.65 | 2.15 | |
| P | .145 | .155 | 3.68 | 3.93 | Dia. |
| R | .055 | .065 | 1.40 | 1.65 | |
| S | .025 | .030 | .64 | .76 | |

TO-208AC (TO-65)

Microsemi
Catalog Number

Forward & Reverse
Repetitive Blocking
VDRM, VRRM

Reverse Transient
Blocking

| | | |
|---------|------|------|
| 40C20B | 200 | 300 |
| 40C40B | 400 | 500 |
| 40C60B | 600 | 700 |
| 40C80B | 800 | 900 |
| 40C100B | 1000 | 1100 |
| 40C120B | 1200 | 1300 |

To specify dv/dt other than 200V/usec., contact factory.

- dv/dt-200 V/usec
- 1000 Amperes surge current
- Economical for medium power applications
- Compact TO-208AC package

Electrical Characteristics

| | | |
|-----------------------------------|-----------------------------|--|
| Max. RMS on-state current | $I_T(\text{RMS})$ 63 Amps | $T_C = 102^\circ\text{C}$ |
| Max. average on-state cur. | $I_T(\text{AV})$ 40 Amps | $T_C = 102^\circ\text{C}$ |
| Max. peak on-state voltage | V_{TM} 3.0 Volts | $I_{TM} = 500 \text{ A(peak)}$ |
| Max. holding current | I_H 200 mA | |
| Max. peak one cycle surge current | I_{TSM} 1000 A | $T_C = 120^\circ\text{C}, 60\text{Hz}$ |
| Max. I^2t capability for fusing | I^2t 4100A ² S | $t = 8.3 \text{ ms}$ |

Thermal and Mechanical Characteristics

| | | |
|-------------------------------|-----------------|--------------------------------|
| Operating junction temp range | T_J | -65°C to 125°C |
| Storage temperature range | T_{STG} | -65°C to 150°C |
| Maximum thermal resistance | $R_{\theta JC}$ | 0.35°C/W Junction to case |
| Typical thermal resistance | $R_{\theta CS}$ | 0.20°C/W Case to sink |
| Mounting torque | | 25-30 inch pounds |
| Weight | | 0.56 ounces (16 grams) typical |

8-31-00 Rev. 2

40C

$T_J = 25^\circ\text{C}$ unless otherwise indicated

| Switching | | | |
|---|---------|------------|---------------------------|
| Critical rate of rise of on-state current (note 1) | di/dt | 200A/usec. | $T_J = 125^\circ\text{C}$ |
| Typical delay time (note 1) | t_d | 3.0 usec. | |
| Typical circuit commuted turn-off time (note 2) | t_q | 100 usec. | $T_J = 125^\circ\text{C}$ |
| Note 1: $I_{TM} = 50\text{A}$, $V_D = V_{DRM}$. $V_{GT} = 12\text{V}$ open circuit, 20 ohm-0.1 usec. rise time Note 2: $I_{TM} = 50\text{A}$, $di/dt = 5\text{A/usec.}$, V_R during turn-off interval = 50V min., reapplied $dv/dt = 20\text{V/usec.}$, linear to rated V_{DRM} , $V_{GT} = 0\text{V}$ | | | |

| Triggering | | | |
|----------------------------------|-------------|-------|---------------------------|
| Max. gate voltage to trigger | V_{GT} | 3.0V | $T_J = 125^\circ\text{C}$ |
| Max. nontriggering gate voltage | V_{GD} | 0.25V | |
| Max. gate current to trigger | I_{GT} | 100mA | $t_p = 10\text{ usec.}$ |
| Max. peak gate power | P_{GM} | 10W | |
| Average gate power | $P_{G(AV)}$ | 1.0W | |
| Max. peak gate current | I_{GM} | 3.0A | |
| Max. peak gate voltage (forward) | V_{GM} | 20V | |
| Max. peak gate voltage (reverse) | V_{GM} | 10V | |

| Blocking | | | |
|--|-----------|------------|--|
| Max. leakage current | I_{DRM} | 6mA | $T_J = 125^\circ\text{C} \ \& \ V_{DRM}$ |
| Max. reverse leakage | I_{RRM} | 6mA | $T_J = 125^\circ\text{C} \ \& \ V_{RRM}$ |
| Critical rate of rise of off-state voltage | dv/dt | 200V/usec. | $T_J = 125^\circ\text{C}$ |

40C

Figure 1
Typical Forward On-State Characteristics

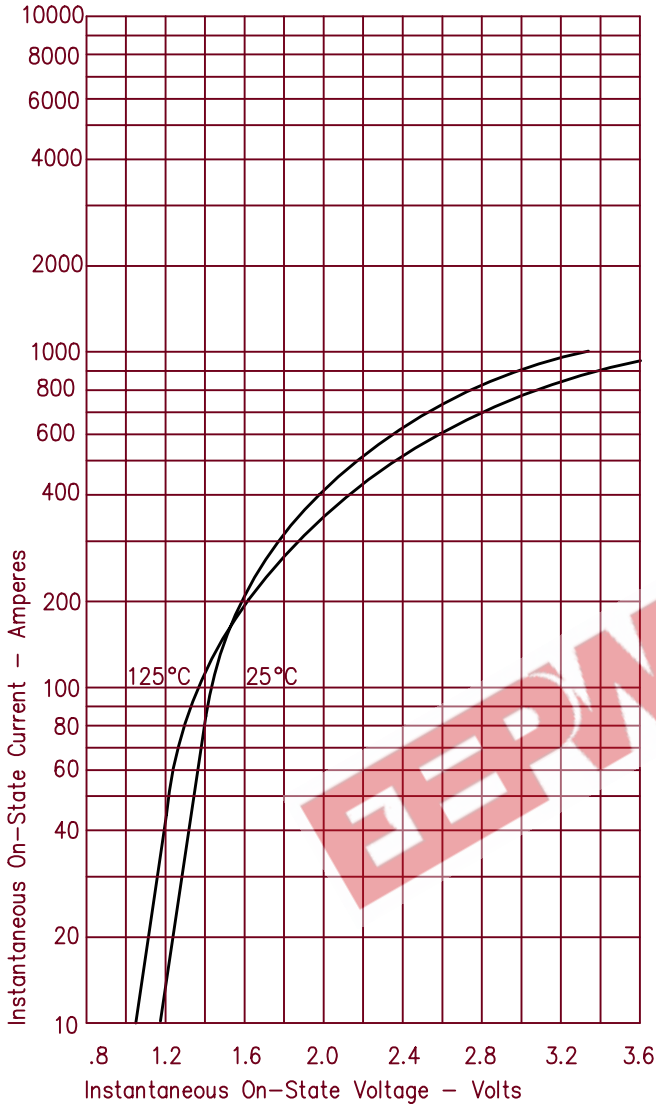


Figure 3
Maximum Power Dissipation

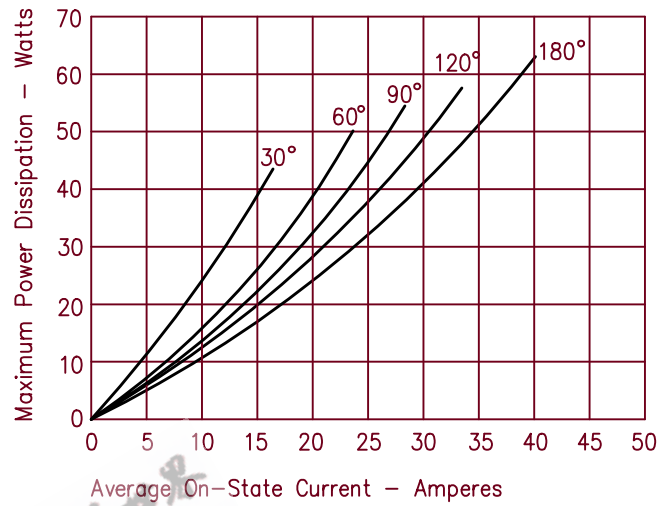


Figure 4
Transient Thermal Impedance

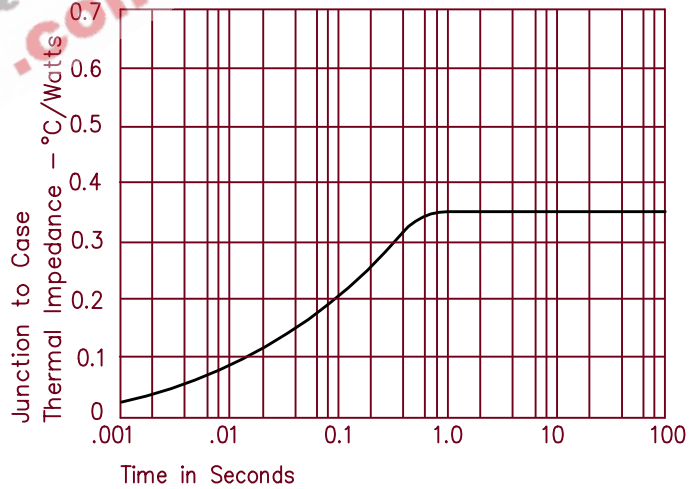


Figure 2
Forward Current Derating

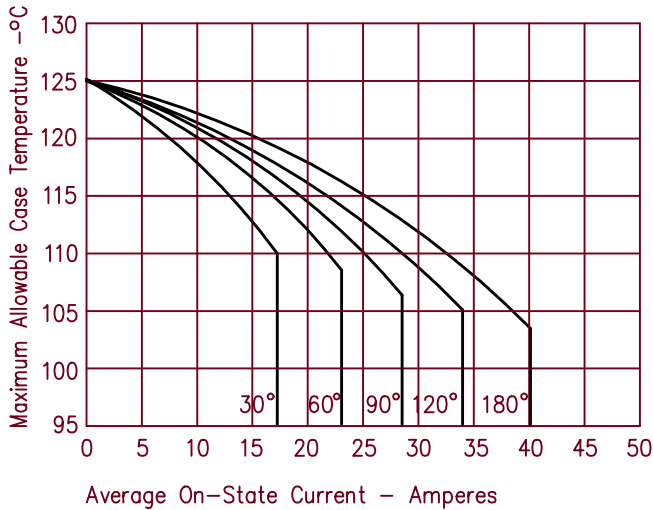


Figure 5
Maximum Nonrepetitive Surge Current

